

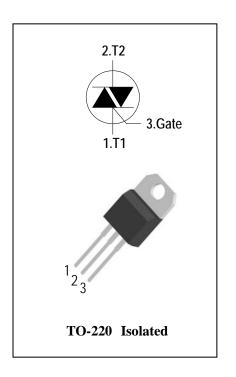
## 3 Quadrants Triacs

### **General Description**

High current density due to mesa technology . the AIS4C triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers.

#### **Features**

- ◆ Repetitive Peak Off-State Voltage: 600Vand800V
- ◆ R.M.S On-State Current (I<sub>T(RMS)</sub>= 4A)
- ◆ High Commutation dv/dt
- ◆ These Devices are Pb-Free and are RoHS Compliant
- ◆ Isolated heatsink mounted , Isolation Voltage ( Viso = 2500V AC )



## **Absolute Maximum Ratings**

Symbol	Items	Conditions		Ratings	Unit
$V_{DRM}$	Depotitive Deals Off State Voltage	T: - 25°C	AIS4C60	600	V
$V_{RRM}$	Repetitive Peak Off-State Voltage	Tj = 25°C	AIS4C80	800	V
$I_{T(RMS)}$	R.M.S On-State Current	T <sub>C</sub> = 105°C		4	Α
$I_{TSM}$	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		25/27	Α
l <sup>2</sup> t	I <sup>2</sup> t for fusing	tp=10ms		3.1	A <sup>2</sup> s
-11/-14	Critical rate of rise of on-state	F = 120 Hz Tj = 125°C I <sub>G</sub> = 2 x I <sub>GT</sub> , tr ≤ 100 ns		50	A/µs
dl/dt	current				
$I_{GM}$	Peak Gate Current	tp = 20 μs Tj = 125°C		2	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=125°C)			0.5	W
$P_GM$	Peak Gate Power Dissipation(tp=20us,Tj=125°C)			5	W
Tj	Operating Junction Temperature			- 40 ~ 125	°C
T <sub>STG</sub>	Storage Temperature			- 40 ~ 150	°C





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## **Electrical Characteristics** (Tj = 25°C unless otherwise specified)

Symbol	Items	Conditions		AIS4C60/80				Unit	
					Т	S	Blank	В	
I <sub>DRM</sub>	Peak Forward Reverse Blocking		V <sub>DRM</sub> = V <sub>RRM</sub> , Tj = 25°C	N.4	5			uA	
I <sub>RRM</sub>	Current		$V_{DRM} = V_{RRM}$ , $Tj = 125$ °C	Max.	1			mA	
V <sub>TM</sub>	Peak On-S	tate Voltage	$I_{TM} = 5 \text{ A}, t_p = 380 \mu \text{s}$	Max.	1.7			V	
$V_{GD}$	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 125^{\circ}\text{C}$	Min.	0.2		V		
$V_{GT}$	Q1-Q2-Q3	Gate Trigger Voltage	V 40V D 000	Max. 1.3			V		
I <sub>GT</sub>	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$ , $R_L = 33\Omega$	Max.	5	10	35	50	mA
I <sub>H</sub>	Q1-Q2-Q3	Holding Current	I <sub>T</sub> = 0.1A	Max.	10	15	40	60	mA
	Q1-Q3	Latching Current	I <sub>G</sub> = 1.2 I <sub>GT</sub>	Max.	10	25	50	70	mA
lι	Q2				15	30	70	80	
dV/dt	Critical Rate of Rise of Off-State  Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 125°C	Min.	20	40	400	1000	V/µs
(dV/dt)c	Rate of Change of Commutating  Current,		(dl/dt)c=-1.7A/ms Tj = 125°C	Min.	0.5	1	10	25	V/µs
R <sub>th(j-c)</sub>	Junction to case (AC)		Max.	4.0			°C/W		
R <sub>th(j-a)</sub>	Junction to ambient		Max.	60				°C/W	

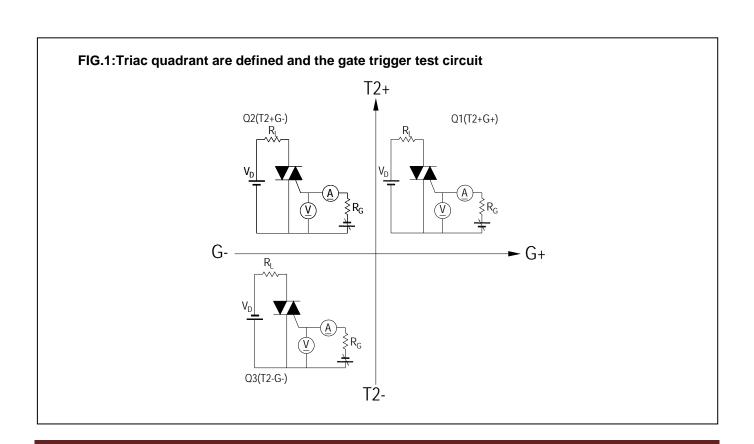




FIG.2: Maximum on-state power dissipation

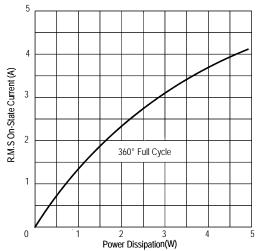


FIG.4: Maximum transient thermal impedance

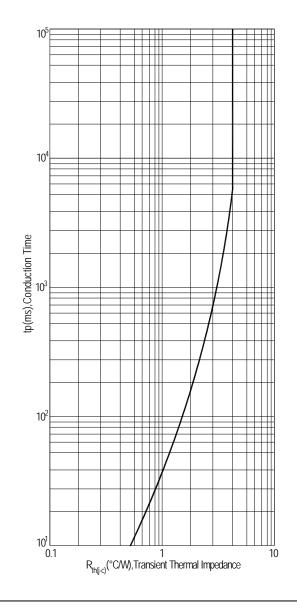


FIG.3: Typical RMS on-state current VS Allowable case Temperature

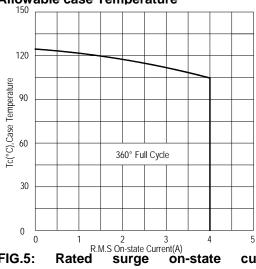


FIG.5: Rated surge on-state current (Non-Repetitive)

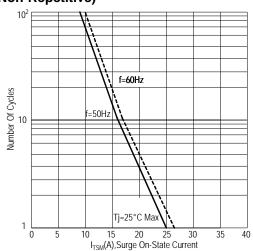


FIG.6: Gate trigger current VS Junction temperature

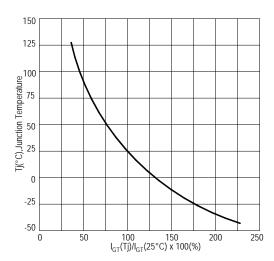




FIG.7:Holding current and Latching current VS Junction temperature

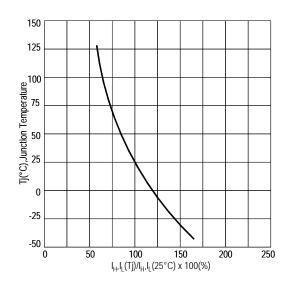


FIG.8: Gate trigger voltage VS Junction temperature

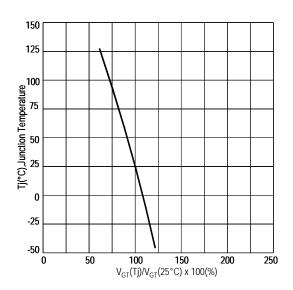
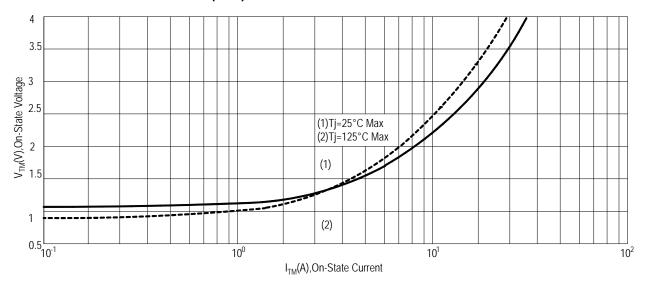


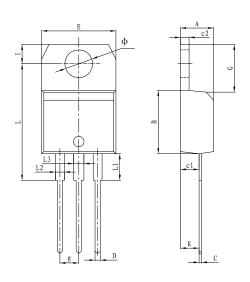
FIG.9: On-state characteristics(Max)



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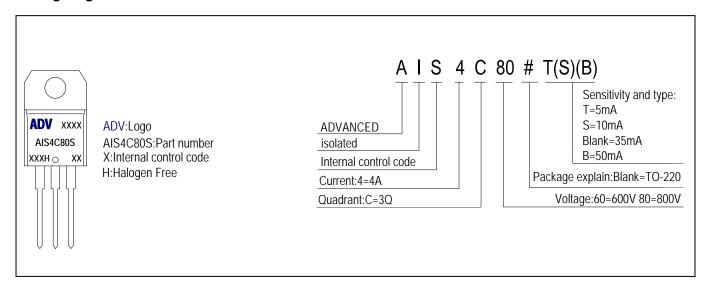


# PACKAGE MECHANICAL DATA TO-220(isolated) Package Dimension



	Dimer	sions	Dimensions			
Symbol	In Milli	meters	In Inches			
	Min	Max	Min	Max		
Α	4.40	4.60	0.173	0.181		
В	9.00	9.30	0.354	0.366		
С	0.40	0.60	0.015	0.023		
c1	2.00	2.60	0.078	0.102		
c2	1.23	1.32	0.048	0.051		
D	0.70	1.00	0.027	0.039		
E	10.00	10.40	0.393	0.409		
g	2.40	2.70	0.094	0.106		
G	6.20	6.80	0.244	0.267		
I	2.65	2.95	0.104	0.116		
L	15.80	16.80	0.622	0.661		
L1	3.75		0.147			
L2	1.14	1.70	0.044	0.066		
L3	1.14	1.70	0.044	0.066		
Ф	3.60	3.90	0.141	0.153		
К	2.60TYP 0.102TYP			2TYP		

#### **Making Diagram**



## **Ordering information**

Part number Package		Marking	Packing	Quantity			
AIS4C60#	TO-220 isolated	AIS4C60#	Tube	50pcs			
AIS4C80#	TO-220 isolated	AIS4C80#	Tube	50pcs			
Note:# = Gate Trigger Current Sensitivity and type							



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